

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

For a detailed explanation of implementing these values in P-Spice, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-Spice Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	9.4938	N/A	9.9253
RT2	2.4395	N/A	4.5035
RT3	24.1011	N/A	5.0138
RT4	48.9656	N/A	1.5574
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	25.3537 m	N/A	145.6245 m
CT2	1.1335 m	N/A	61.6563 m
CT3	68.8236 m	N/A	12.6087 m
CT4	1.1715	N/A	2.6992 m

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance ($^{\circ}\text{C}/\text{W}$)			
Junction to	Ambient	Case	Foot
RF1	3.4531	N/A	2.7234
RF2	19.7740	N/A	7.6947
RF3	15.8765	N/A	1.7987
RF4	45.8964	N/A	8.7832
Thermal Capacitance (Joules/ $^{\circ}\text{C}$)			
Junction to	Ambient	Case	Foot
CF1	1.2966 m	N/A	2.2407 m
CF2	21.9384 m	N/A	10.1473 m
CF3	72.0132 m	N/A	45.3693 m
CF4	1.1501	N/A	74.0549 m

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

